



VOLTAGE RANGE: 50 --- 800 V

CURRENT: 2.0 A

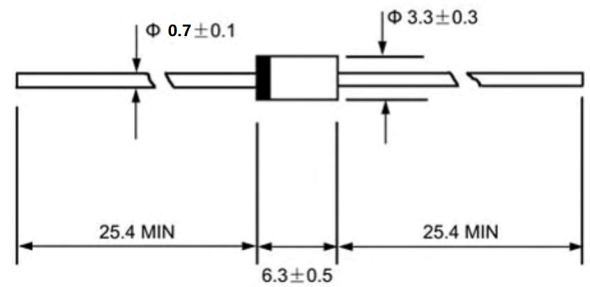
DO - 15

Features

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

Mechanical Data

- ◇ Case: JEDEC DO--15, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-750, Method 2026
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.014 ounces, 0.39 grams
- ◇ Mounting position: Any



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		EGP 20A	EGP 20B	EGP 20C	EGP 20D	EGP 20F	EGP 20G	EGP 20J	EGP 20K	UNITS	
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	150	200	300	400	600	800	V	
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	420	560	V	
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	600	800	V	
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ\text{C}$	$I_{F(AV)}$	2.0								A	
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	I_{FSM}	75								A	
Maximum instantaneous forward voltage @ 2.0 A	V_F	0.95			1.25		1.7			V	
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=125^\circ\text{C}$	I_R	5.0				100					μA
Maximum reverse recovery (Note1)	t_{rr}	50					75				ns
Typical junction capacitance (Note2)	C_J	70					45				pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	40								$^\circ\text{C}/\text{W}$	
Typical thermal resistance (Note4)	$R_{\theta JL}$	15									
Operating junction temperature range	T_J	- 55 ---- + 150								$^\circ\text{C}$	
Storage temperature range	T_{STG}	- 55 ---- + 150								$^\circ\text{C}$	

NOTE: 1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{rr}=0.25\text{A}$.

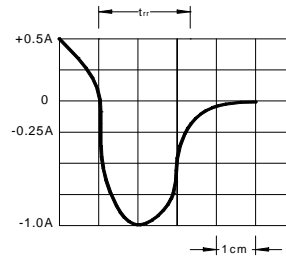
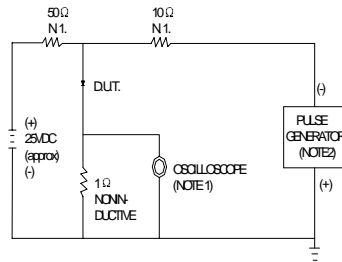
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

4. Thermal resistance from junction to lead.

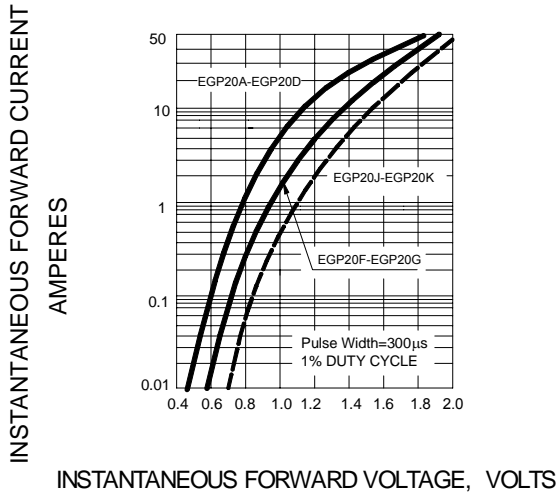
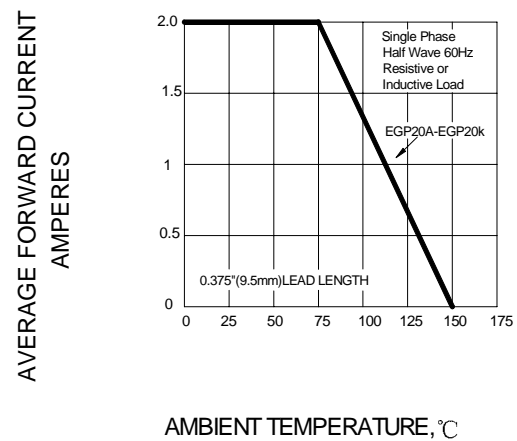
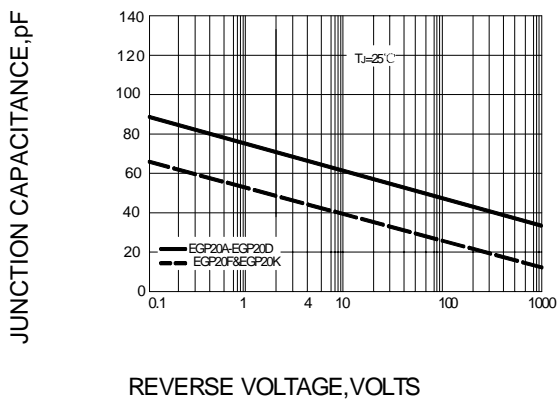
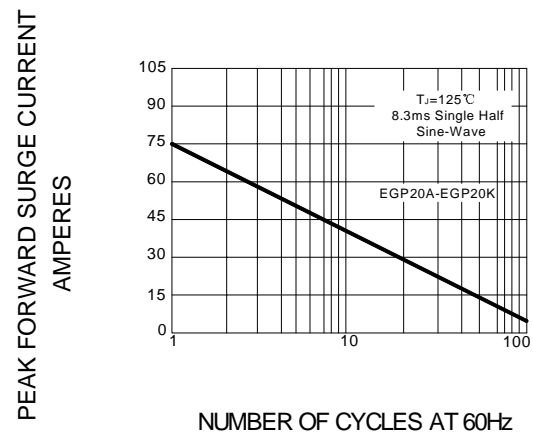


Ratings AND Characteristic Curves

FIG.1 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC


NOTES: 1. RISE TIME = 7ns MAX INPUT IMPEDANCE = 1MΩ .22pF.
2. RISE TIME = 10ns MAX SOURCE IMPEDANCE = 50 Ω.

SET TIME BASE FOR 20/30 ns/cm

FIG.2 – TYPICAL FORWARD CHARACTERISTIC

FIG.3 – FORWARD DERATING CURVE

FIG.4 – TYPICAL JUNCTION CAPACITANCE

FIG.5 – PEAK FORWARD SURGE CURRENT


PACKAGE	SPQ/PCS	CARTON SPQ/PCS	CARTON SIZE/CM	CARTON GW/KG	CARTON NW/KG
DO-15	3000/AMMO	30000	42X28X31	12.00	10.00